

Technical Data Data Sheet 4944, Rev.-

SILICON SCHOTTKY RECTIFIER DIE Extremely Low Forward Voltage Drop

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

Maximum Ratings(1):

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	15	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle, rectangular wave form	3	Α
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine wave	55	Α
Non-Repetitive Avalanche Energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, \ I_{AS} = 1.3 \text{A}, \ L = 6.7 \text{mH}$	5.6	mJ
Repetitive Avalanche Current	I _{AR}	I_{AS} decay linearly to 0 in 1 μ s f limited by T_J max V_A =1.5 V_R	1.3	Α
Max. Junction Temperature	TJ	-	-65 to +100	°C
Max. Storage Temperature	T _{stg}	-	-65 to +100	°C

Electrical Characteristics(1):

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 3A, Pulse, T _J = 25 °C	0.37	V
	V_{F2}	@ 3A, Pulse, T _J = 100 °C	0.33	V
Max. Reverse Current	I _{R1}	@V _R = 45V, Pulse,	1.5	mA
		$T_J = 25 ^{\circ}C$		
	I _{R2}	@V _R = 45V, Pulse,	70	mA
		T _J = 100 °C		
Max. Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 ^{\circ}C$	240	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

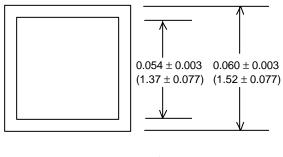
(1) in SHD package

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Mechanical Dimensions: In Inches / mm

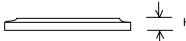


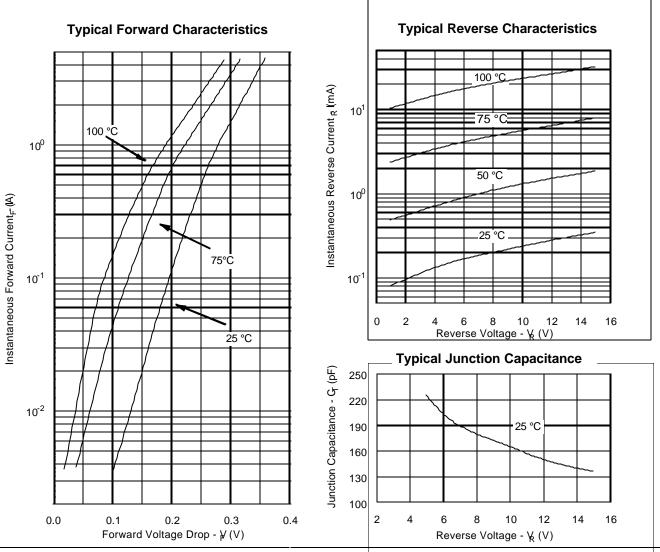
Bottom side metalization Ag - 30 kÅ minimum.

Top side metalization Al - 25 kÅ minimum or Ag - 30 kÅ minimum.

Bottom side is cathode, top side is anode.

Dimension H = 0.0105 \pm 0.001 (0.27 \pm 0.026) for Al top; Dimension H = 0.0155 \pm 0.001 (0.39 \pm 0.026) for Ag top.





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